# 2SK2114, 2SK2115

#### Silicon N-Channel MOS FET

# **HITACHI**

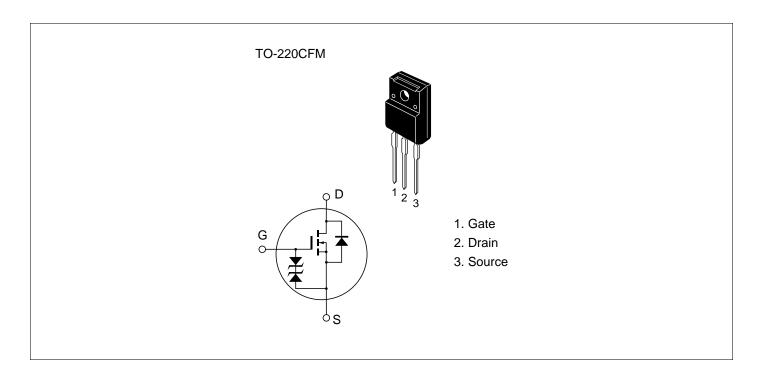
#### **Application**

High speed power switching

#### **Features**

- Low on-resistance
- High speed switching
- Low drive current
- No secondary breakdown
- Suitable for Switching regulator

#### **Outline**





## 2SK2114, 2SK2115

### **Absolute Maximum Ratings** $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit	
Drain to source voltage	2SK2114	$V_{\scriptscriptstyle DSS}$	450	V	
	2SK2115	$V_{\mathtt{DSS}}$	500		
Gate to source voltage		$V_{\sf GSS}$	±30	V	
Drain current		I <sub>D</sub>	5	А	
Drain peak current	l *1 D(pulse)	20	Α		
Body to drain diode reverse drain current		I <sub>DR</sub>	5	А	
Channel dissipation		Pch*2	35	W	
Channel temperature		Tch	150	°C	
Storage temperature	Tstg	-55 to +150	°C		

Notes 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1 %

2. Value at Tc = 25 °C

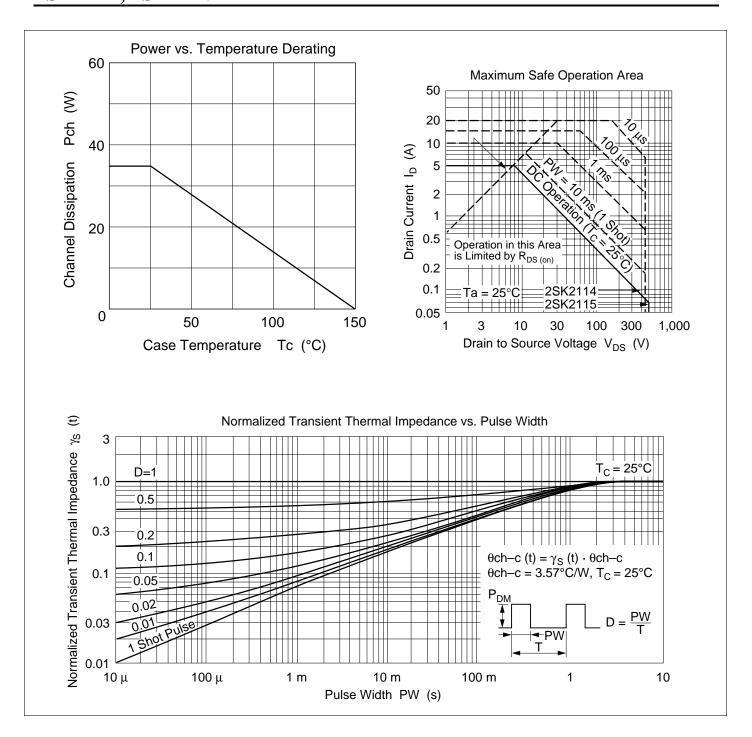
### **Electrical Characteristics** ( $Ta = 25^{\circ}C$ )

Item		Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source	2SK2114	$V_{(BR)DSS}$	450	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
breakdown voltage	2SK2115		500				
Gate to source b voltage	reakdown	$V_{(BR)GSS}$	±30	_	_	V	$I_{G} = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source le	ak current	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0$
Zero gate	2SK2114	I <sub>DSS</sub>	_		250	μΑ	$V_{DS} = 360 \text{ V}, V_{GS} = 0$
voltage drain current	2SK2115						$V_{DS} = 400 \text{ V}, V_{GS} = 0$
Gate to source co	utoff voltage	$V_{GS(off)}$	2.0		3.0	V	$I_{D} = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to	2SK2114	R <sub>DS(on)</sub>	_	1.0	1.4	Ω	$I_D = 2.5 \text{ A}, V_{GS} = 10 \text{ V}^{*1}$
source on state resistance	2SK2115		_	1.2	1.5		
Forward transfer	admittance	y <sub>fs</sub>	2.5	4.0	_	S	$I_D = 2.5 \text{ A}$ $V_{DS} = 10 \text{ V}^{*1}$
Input capacitance	Э	Ciss	_	640	_	pF	V <sub>DS</sub> = 10 V
Output capacitan	се	Coss	_	160	_	pF	$V_{GS} = 0$
Reverse transfer	capacitance	Crss	_	20	_	pF	f = 1 MHz
Turn-on delay tim	ne	t <sub>d(on)</sub>	_	10	_	ns	I <sub>D</sub> = 2.5 A
Rise time		t <sub>r</sub>	_	25	_	ns	V <sub>GS</sub> = 10 V
Turn-off delay tim	ne	t <sub>d(off)</sub>		50	_	ns	$R_L = 12 \Omega$
Fall time		t <sub>f</sub>		30	_	ns	
Body to drain dio voltage	de forward	$V_{DF}$	_	0.95	_	V	$I_F = 5 \text{ A}, V_{GS} = 0$
Body to drain dio recovery time	de reverse	t <sub>rr</sub>	_	300	_	ns	$I_F = 5 \text{ A}, V_{GS} = 0,$ $di_F / dt = 100 \text{ A} / \mu \text{s}$

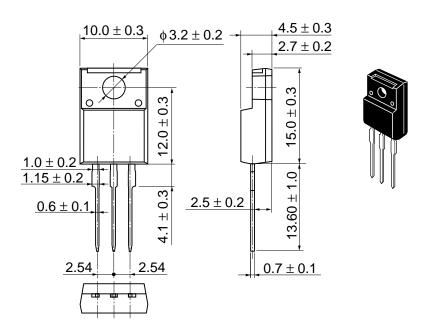
Note 1. Pulse Test

See characteristics curve of 2SK1155, 2SK1156.

### 2SK2114, 2SK2115



Unit: mm



Hitachi Code	TO-220CFM			
JEDEC	_			
EIAJ	_			
Weight (reference value)	1.9 g			

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